

1. Global joint venture starts operations as WeEn Semiconductors

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As from November 9th, 2015 NXP Semiconductors N.V. and Beijing JianGuang Asset Management Co. Ltd established Bipolar Power joint venture (JV), **WeEn Semiconductors**, which will be used in future Bipolar Power documents together with new contact details.

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Thank you for your cooperation and understanding,

WeEn Semiconductors





1. General description

Planar passivated Silicon Controlled Rectifier with sensitive gate in a SOT54 (TO-92) plastic package. This SCR is designed to be interfaced directly to microcontrollers, logic ICs and other low power gate trigger circuits.

2. Features and benefits

- Enhanced voltage capability
- · Planar passivated for voltage ruggedness and reliability
- Sensitive gate
- Direct triggering from low power drivers and logic ICs

3. Applications

· General purpose switching and phase control

4. Quick reference data

Table 1. Quick reference data

Tubic I. Quick	reference data					
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V _{DRM}	repetitive peak off- state voltage		-	-	600	V
V _{RRM}	repetitive peak reverse voltage		-	-	600	V
I _{TSM}	non-repetitive peak on- state current	half sine wave; T _{j(init)} = 25 °C; t _p = 10 ms; <u>Fig. 4</u> ; <u>Fig. 5</u>	-	-	8	A
		half sine wave; T _{j(init)} = 25 °C; t _p = 8.3 ms	-	-	9	A
Tj	junction temperature		-	-	125	°C
I _{T(AV)}	average on-state current	half sine wave; T _{lead} ≤ 83 °C; <u>Fig. 1</u>	-	-	0.5	A
I _{T(RMS)}	RMS on-state current	half sine wave; T _{lead} ≤ 83 °C; <u>Fig. 2;</u> <u>Fig. 3</u>	-	-	0.8	A
Static charact	teristics	·				
I _{GT}	gate trigger current	V _D = 12 V; I _T = 10 mA; T _j = 25 °C; <u>Fig. 7</u>	-	50	200	μA
Dynamic char	racteristics	·				_
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 402 V; T _j = 125 °C; R _{GK} = 1 kΩ; (V_{DM} = 67% of V_{DRM}); exponential waveform; Fig. 12	500	800	-	V/µs

5. Ordering information

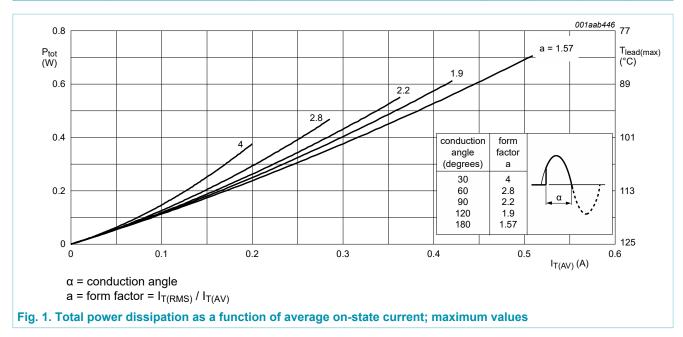
Table 2. Ordering information						
Type number	Package					
	Name	Description	Version			
BT149G	TO-92	plastic single-ended leaded (through hole) package; 3 leads	SOT54			

6. Limiting values

Table 3. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

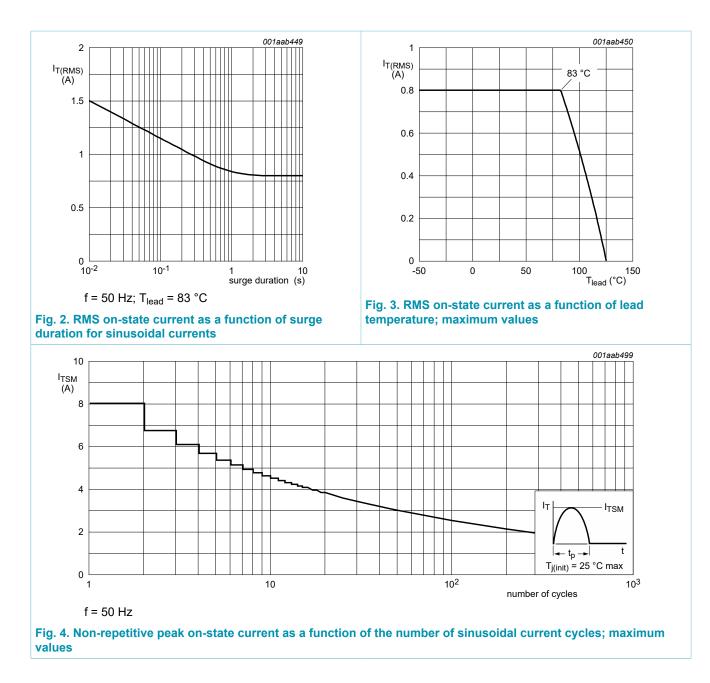
Symbol	Parameter	Conditions	Min	Max	Unit
V _{DRM}	repetitive peak off-state voltage		-	600	V
V _{RRM}	repetitive peak reverse voltage		-	600	V
I _{T(AV)}	average on-state current	half sine wave; T _{lead} ≤ 83 °C; <u>Fig. 1</u>	-	0.5	А
I _{T(RMS)}	RMS on-state current	half sine wave; T _{lead} ≤ 83 °C; <u>Fig. 2</u> ; <u>Fig. 3</u>	-	0.8	А
I _{TSM}	non-repetitive peak on- state current	half sine wave; $T_{j(init)} = 25 \text{ °C}$; $t_p = 10 \text{ ms}$; Fig. 4; Fig. 5	-	8	A
		half sine wave; T _{j(init)} = 25 °C; t _p = 8.3 ms	-	9	А
l ² t	I ² t for fusing	t _p = 10 ms; SIN	-	0.32	A²s
dl _T /dt	rate of rise of on-state current	I _T = 2 A; I _G = 10 mA; dI _G /dt = 100 mA/μs	-	50	A/µs
I _{GM}	peak gate current		-	1	А
V _{RGM}	peak reverse gate voltage		-	5	V
P _{GM}	peak gate power		-	2	W
P _{G(AV)}	average gate power	over any 20 ms period	-	0.1	W
T _{stg}	storage temperature		-40	150	°C
Tj	junction temperature		-	125	°C



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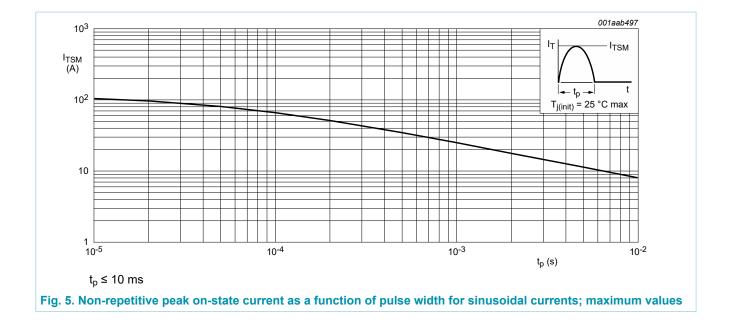
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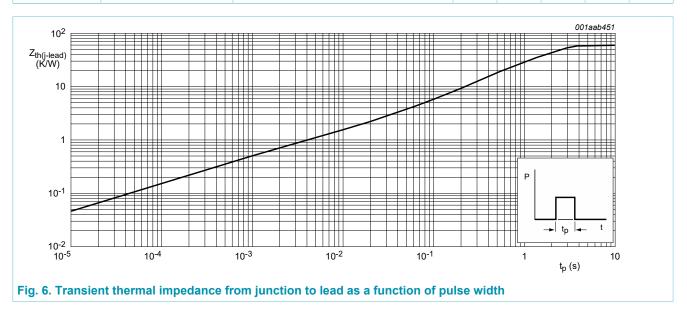
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7. Thermal characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$R_{th(j-lead)}$	thermal resistance from junction to lead	<u>Fig. 6</u>	-	-	60	K/W
R _{th(j-a)}	thermal resistance from junction to ambient free air	printed circuit board mounted: lead length = 4 mm	-	150	-	K/W



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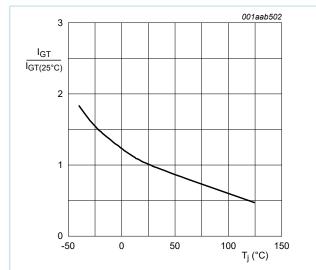
8. Characteristics

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
Static chara	icteristics	· · · · ·				
GT	gate trigger current	V _D = 12 V; I _T = 10 mA; T _j = 25 °C; <u>Fig. 7</u>	-	50	200	μA
L	latching current	V_D = 12 V; I _G = 0.5 mA; T _j = 25 °C; R _{GK(ext)} = 1 kΩ; <u>Fig. 8</u>	-	2	6	mA
Н	holding current	V_D = 12 V; T _j = 25 °C; R _{GK(ext)} = 1 kΩ; Fig. 9	-	2	5	mA
V _T	on-state voltage	I _T = 1.2 A; T _j = 25 °C; <u>Fig. 10</u>	-	1.25	1.7	V
V _{GT}	gate trigger voltage	V _D = 12 V; I _T = 10 mA; T _j = 25 °C; <u>Fig. 11</u>	-	0.5	0.8	V
		V _D = 600 V; I _T = 10 mA; T _j = 125 °C; <u>Fig. 11</u>	0.2	0.3	-	V
I _D	off-state current	V_D = 600 V; $R_{GK(ext)}$ = 1 k Ω ; T_j = 125 °C	-	0.05	0.1	mA
I _R	reverse current	V_R = 600 V; T_j = 125 °C; $R_{GK(ext)}$ = 1 k Ω	-	0.05	0.1	mA
Dynamic ch	aracteristics					
dV _D /dt	rate of rise of off-state voltage	V_{DM} = 402 V; T _j = 125 °C; R _{GK} = 1 kΩ; (V_{DM} = 67% of V_{DRM}); exponential waveform; Fig. 12	500	800	-	V/µs
		V_{DM} = 402 V; T _j = 125 °C; (V _{DM} = 67% of V _{DRM}); exponential waveform; gate open circuit; Fig. 12	-	2	-	V/µs
t _{gt}	gate-controlled turn-on time	I_{TM} = 2 A; V _D = 600 V; I _G = 10 mA; dI _G / dt = 0.1 A/µs; T _j = 25 °C	-	2	-	μs
tq	commutated turn-off time	$V_{DM} = 402 \text{ V}; \text{ T}_{j} = 125 \text{ °C}; \text{ I}_{TM} = 1.6 \text{ A};$ $V_{R} = 35 \text{ V}; (dI_{T}/dt)_{M} = 30 \text{ A}/\mu\text{s}; dV_{D}/$ $dt = 2 \text{ V}/\mu\text{s}; \text{ R}_{GK(ext)} = 1 \text{ k}\Omega; (V_{DM} = 67\% \text{ of } V_{DRM})$	-	100	-	μs

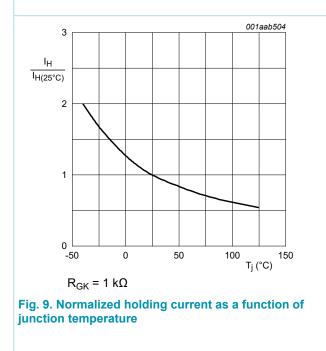
Product data sheet

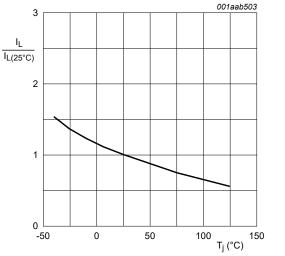
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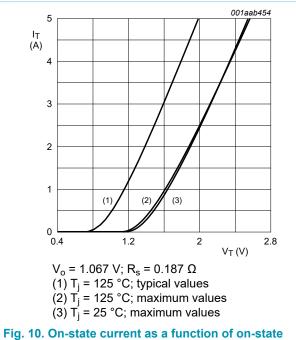








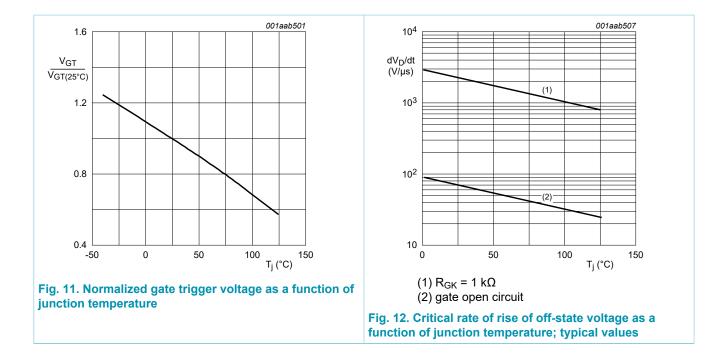




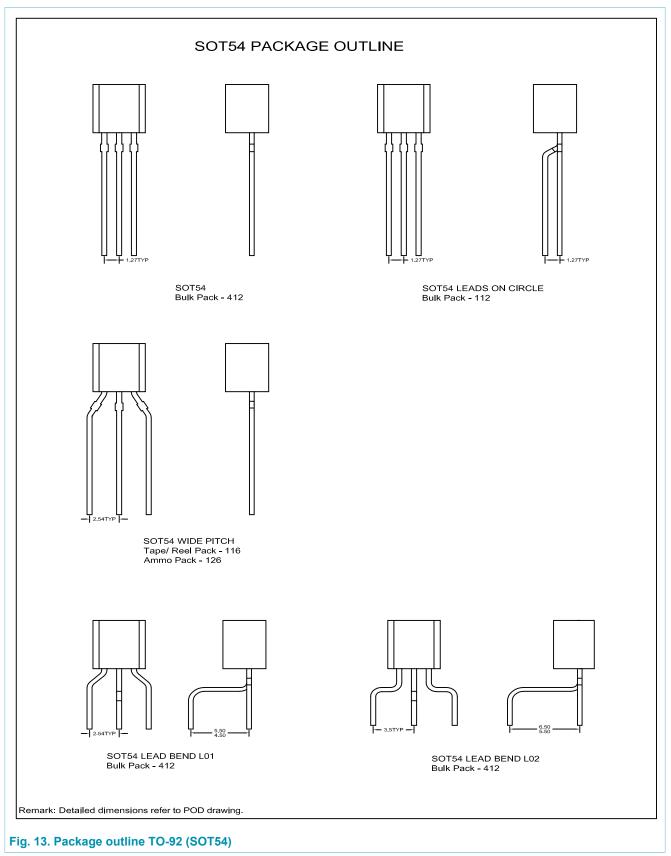
voltage

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9. Package outline



Product data sheet

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10. Legal information

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Document status [1][2]	Product status [<u>3]</u>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

[1] Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
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